

Phonon emission and arrival times of electrons from a single-electron source

C. Emary* and A. Dyson

Department of Physics and Mathematics, University of Hull, Kingston-upon-Hull HU6 7RX, United Kingdom

Sungguen Ryu and H.-S. Sim

Department of Physics, Korea Advanced Institute of Science and Technology, Daejeon 305-701, Republic of Korea

M. Kataoka

National Physical Laboratory, Hampton Road, Teddington, Middlesex TW11 0LW, United Kingdom

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In recent charge-pump experiments, single electrons are injected into quantum Hall edge channels at energies significantly above the Fermi level. We consider here the relaxation of these hot edge-channel electrons through longitudinal-optical-phonon emission. Our results show that the probability for an electron in the outermost edge channel to emit one or more phonons en route to a detector some microns distant along the edge channel suffers a double-exponential suppression with increasing magnetic field. This explains recent experimental observations. We also describe how the shape of the arrival-time distribution of electrons at the detector reflects the velocities of the electronic states post phonon emission. We show how this can give rise to pronounced oscillations in the arrival-time-distribution width as a function of magnetic field or electron energy.

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I. INTRODUCTION

Single-electron sources have recently been realized with a number of different technologies such as driven mesoscopic capacitors [1], quantum-dot charge pumps [2–8], and surface acoustic waves [9–11]. Shaped voltage pulses have also been used to generate single Levitons [12]. These sources enable electronic analogs of fundamental quantum-optics experiments [13–15], and hold great promise for future application, in particular as a current standard [16]. For the full potential of these sources to be realized, however, we need an understanding of the relaxation and decoherence processes that affect their single-electron outputs [17–20].

The focus of the current paper is the effect of longitudinal-optical (LO) phonon emission by the hot electrons originating from the charge pumps of Refs. [4–8]. In these systems, single electrons are emitted by a dynamically driven quantum dot into quantum-Hall edge channels. The emission energy of these electrons can be controlled by adjusting the dot potentials [7,21] and can be set far above the Fermi sea. By means of an adjustable detector barrier height some 2–5 μm downstream of the emitter, these experiments offer both energy- and time-resolved detection of the electrons [7,8].

In Ref. [7] it was reported that, at certain magnetic-field strengths, a significant fraction of the electrons arrive at the detector with an energy that is some integer multiple of ~ 36 meV less than their energy at emission. Since 36 meV corresponds approximately to the energy of LO phonons in GaAs [22], it was concluded that these electrons had emitted one or more LO phonons en route to the detector. Moreover, Fletcher *et al.* [7] report that while these “phonon replica” features are pronounced at lower fields ($B = 6$ T),

they are scarcely visible at high fields ($B = 12$ T). A similar observation was made for different samples in Ref. [8].

In this paper we offer an explanation of this transition based on the localization properties of edge-channel wave functions in a magnetic field. Using a Fröhlich Hamiltonian [23,24], we calculate scattering rates out of individual edge-channel states as a function of field strength and energy of emission. From this we obtain the probability of electrons emitting $m = 0, 1, 2, \dots$ LO phonons before reaching the detector. For electrons emitted into the outermost edge channel, we find an abrupt transition, essentially from 0 to 1, in the probability that no phonons are emitted. We also discuss phonon emission by electrons in edge channels other than the outermost, and describe conditions under which anomalously large values of the relaxation rates can occur.

We then go on to consider the distribution of electron arrival times at the detector. This distribution is similar in concept to the waiting time distribution,¹ which has been studied for time-independent transport in Coulomb-blockade systems [25] and also for a dynamic single-electron emitter [26]. Here, we calculate the arrival-time distributions (ATDs) for electrons having emitted different numbers of phonons and show how energy loss leads to an increase in the widths of the phonon-replica distributions. We also predict that at lower fields the widths of these distributions show pronounced oscillations as a function of emission energy or magnetic field. This effect originates from the scattering of electrons into different edge channels as the field or energy is changed.

This paper is structured as follows. In Sec. II we recap the properties of quantum-Hall edge states with parabolic

*Present address: Joint Quantum Centre (JQC) Durham-Newcastle, School of Mathematics and Statistics, Newcastle University, Newcastle upon Tyne, NE1 7RU, United Kingdom.

¹Whereas the waiting-time distribution studies correlations between successive events in a stochastic process, the arrival-time distribution looks at event statistics relative to some fixed time, here the starting emission time.

transverse confinement and in Sec. III we derive an expression for the scattering rate between these states. The ATDs are discussed in Sec. IV, before we finish with discussions in Sec. V.

II. ELECTRON STATES

The charge pumps in question emit single electrons into the edge channels of a two-dimensional electron gas in the quantum-Hall regime. We model the behavior of these electrons in the xy plane with the effective-mass Schrödinger equation [27] ($e > 0$),

$$H = \frac{1}{2m_e^*}(i\hbar\nabla - e\mathbf{A})^2 + U(y), \quad (1)$$

with m_e^* the effective electron mass, \mathbf{A} the vector potential, and $U(y)$ the confinement potential transverse to the transport direction. With magnetic field B perpendicular to the plane, the vector potential in the Landau gauge reads $\mathbf{A} = -By\hat{\mathbf{i}}$, with $\hat{\mathbf{i}}$ a unit vector in the x direction. We consider a parabolic confinement with confinement energy $\hbar\omega_y$, such that $U(y) = \frac{1}{2}m_e^*\omega_y^2 y^2$. We discuss the limits of this model in describing the experiments of Refs. [7,8] at the end of this section.

The eigenfunctions of H are plane waves in the x direction with wave number k and harmonic-oscillator eigenfunctions in the y direction with quantum number $n = 0, 1, 2, \dots$ (see Appendix A). The transverse wave functions are localized about a guiding-center coordinate

$$y_G(k) = \frac{\omega_c^2}{\Omega^2} \frac{\hbar k}{eB}, \quad (2)$$

and have a characteristic width

$$l_\Omega = \sqrt{\frac{\hbar}{m_e^* \Omega}}. \quad (3)$$

Here, Ω is the composite frequency $\Omega = \sqrt{\omega_y^2 + \omega_c^2}$ with $\omega_c = \frac{|eB|}{m_e^*}$, the cyclotron frequency. The energies of the eigenstates read

$$E_{nk} = \hbar\Omega \left\{ n + \frac{1}{2} + \frac{1}{2} \left[\frac{\omega_y y_G(k)}{\omega_c l_\Omega} \right]^2 \right\}, \quad (4)$$

with corresponding velocities

$$v_{nk} = \frac{1}{\hbar} \frac{\partial E_{nk}}{\partial k} = \frac{\omega_y^2}{\omega_c} y_G. \quad (5)$$

Recent measurements [28] of the velocities of the electrons emitted by the charge pumps show that, close to edge of the sample, the transverse potential is well approximated by the quadratic form employed here. Across the interior of the sample, however, the potential is expected to be essentially flat. The experimental potential is therefore an open parabola, rather than the closed one we consider here. Nevertheless, we expect the eigenfunctions of the closed parabola to provide a good approximation to those of the open one provided that their displacement from the origin is significantly greater than their spatial extent, i.e., when $y_G \gg l_\Omega$. This implies that the energy of the electron above its subband bottom should satisfy

$$E - \hbar\Omega \left(n + \frac{1}{2} \right) \gg \frac{\hbar\Omega}{2} \left(\frac{\omega_y}{\omega_c} \right)^2. \quad (6)$$

This holds true for most of the results reported here. In the cases where it does not, we will argue that our results still give a qualitative guide to experiment.

III. PHONON RELAXATION RATES

The scattering of quantum-confined electrons by phonons, both with [22,29–31] and without [32,33] magnetic field, has been studied extensively. These previous studies, however, have focused on macroscopic properties such as conductance or optical absorption. In contrast, our analysis here concerns the fate of single electrons and scattering rates between individual edge-channel states.

We describe the interaction between electrons and LO phonons with the Fröhlich Hamiltonian [23,24] which, in terms of the electronic states described above, can be written as

$$V_{\text{ep}} = \sum_{nn'} \sum_{kk'} \sum_{\mathbf{q}} \Lambda_{n'n}^{k'k}(\mathbf{q}) c_{n'k}^\dagger c_{nk} (a_{-\mathbf{q}}^\dagger + a_{\mathbf{q}}). \quad (7)$$

Here c_{nk} is the annihilation operator for electrons with quantum numbers n and k , $a_{\mathbf{q}}$ is the annihilation operator for bulk LO phonons with (three-dimensional) wave vector \mathbf{q} , and $\Lambda_{n'n}^{k'k}(\mathbf{q})$ is the appropriate matrix element, proportional to the dimensionless Fröhlich coupling constant α . The form of this matrix element along with some technical details on the following calculation are discussed in Appendix B. We assume that the phonons are dispersionless and have energy $\hbar\omega_{\text{LO}}$.

We consider the zero-temperature limit and phonon emission only. Since in GaAs the coupling constant is small ($\alpha \approx 0.068$), we work to lowest order in α and calculate the effects of coupling to the phonons via Fermi's “golden rule” [34]. This gives the rate of transition from the state in subband n with energy E to a state in subband n' with energy $E - \hbar\omega_{\text{LO}}$ to be

$$\Gamma_{n'n}(E) = \frac{\alpha\Omega\omega_{\text{LO}}}{2\pi\omega_y} \sqrt{\frac{\hbar\omega_{\text{LO}}}{\Delta_{n'}}} \Theta(\Delta_{n'}) I_{n'n}(\delta_G). \quad (8)$$

Here, $\Delta_{n'}(E) \equiv E - \hbar\Omega(n' + \frac{1}{2}) - \hbar\omega_{\text{LO}}$ is the energy taken up by the motion along the edge channel after the transition, Θ is the unit-step function, and $I_{n'n}$ is a one-dimensional integral, the argument of which is the relative change in guide center,

$$\delta_G = \frac{y_G - y'_G}{l_\Omega}, \quad (9)$$

with y_G associated with the initial state (subband n) and y'_G with the final state (subband n'). The full form of this one-dimensional integral is discussed in Appendix B. However, when the initial energy of the electron is the dominant energy scale, we obtain the approximate form

$$I_{n'0}(\delta_G) \approx \pi^{3/2} \frac{\omega_c}{\Omega} \frac{1}{n!} \left(\frac{\delta_G^2}{2} \right)^{n'-(1/2)} e^{-(1/2)\delta_G^2}, \quad (10)$$

where, for simplicity of presentation, we quote the result for $n = 0$ only. Thus, the rates are dominated by an exponential dependence on the distance between guiding centers before and after scattering. This dependence arises from the overlap of the transverse wave functions. In emitting a phonon, an electron loses energy and, if starting in the outermost subband,

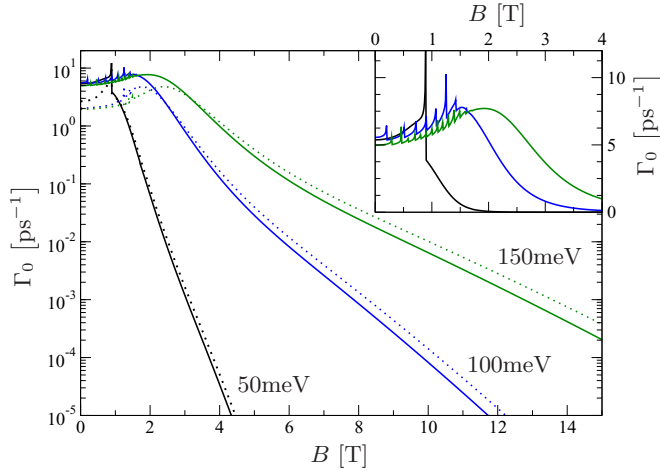


FIG. 1. The total phonon-induced scattering rate $\Gamma_0 = \Gamma_0(E)$ out of the $n = 0$ edge channel as a function of magnetic field for several initial electron energies, $E = 50, 100, 150$ meV. The main panel shows results out to $B = 15$ T for both the full expression of Eq. (8) (solid lines) as well as the approximate form of Eq. (10) (dashed lines). The inset shows the low-field region. Parameters for the calculation were as follows: transverse confinement energy $\hbar\omega_y = 2.7$ meV, electron-phonon coupling constant $\alpha = 0.068$, effective mass $m_e^* = 0.067m_e$, and phonon energy $\hbar\omega_{LO} = 36$ meV. We also assumed a confinement distance of $a = 5$ nm perpendicular to the plane (see Appendix A).

its k value is correspondingly reduced. Since the guiding center of the edge-channel wave functions is proportional to k , states before and after emission are then necessarily separated in the y direction. At large field and/or energies, the overlap of these two wave functions is through their exponential tails, and hence the form of Eq. (10).

Considering first the transition within the outermost edge channel ($n = n' = 0$), we have

$$\delta_G^2 = \frac{2\omega_c^2}{\omega_y^2 \hbar \Omega} \left[\sqrt{E - \frac{1}{2}\hbar\Omega} - \sqrt{E - \hbar\omega_{LO} - \frac{1}{2}\hbar\Omega} \right]^2.$$

If the energies of the problem are ordered $E - \hbar\omega_{LO} \gg \hbar\omega_c \gg \hbar\omega_y$, this simplifies such that we may write

$$\Gamma_{00}(E) \sim \exp[-B/B_T], \quad (11)$$

with

$$B_T = \frac{m\hbar\omega_y^2}{eE} \left(1 - \sqrt{1 - \frac{\hbar\omega_{LO}}{E}} \right)^{-2}. \quad (12)$$

This transition field increases with increasing electron energy and also with increasing confinement. For higher field strengths, terms proportional to B^2 start to play a role in the exponent.

Considering the case for general n and n' , in the same approximation as above and with $E \gg \hbar\omega_{LO}$, the exponential part of the rate reads

$$\Gamma_{n'n}(E) \sim \exp \left[-\frac{1}{4E} \frac{(\hbar\omega_c)^2}{\hbar\Omega} \left(\frac{\omega_{LO}}{\omega_y} \right)^2 \left\{ 1 + \frac{\Omega}{\omega_{LO}}(n' - n) \right\}^2 \right]. \quad (13)$$

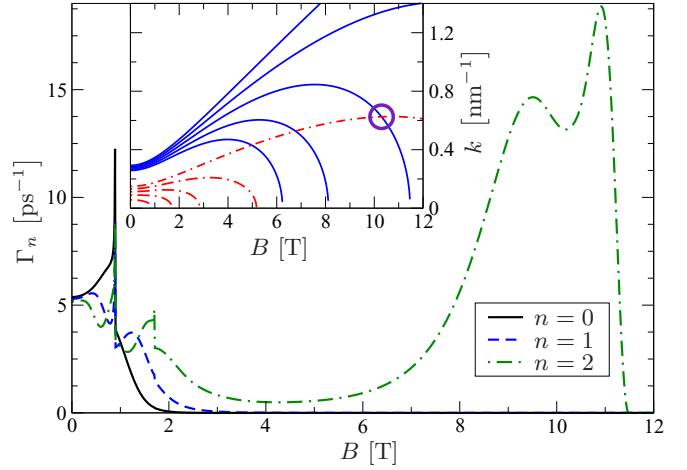


FIG. 2. Main panel: Total scattering rate $\Gamma_n = \Gamma_n(E)$ out of the $n = 0, 1, 2$ edge channel as a function of magnetic field with an initial electron energy of $E = 50$ meV. The most striking feature is the anomalously high rate for the $n = 2$ state centered around a field of $B \approx 10$ T. Inset: This phenomenon can be understood by considering the wave numbers involved in scattering as a function of magnetic field. The solid blue lines show the wave numbers of initial states at $E = 50$ meV as a function of magnetic field. The uppermost line is from the $n = 0$ subband, with lines progressing downward corresponding to $n = 1, \dots, 4$. The dashed red lines show the same thing but at an energy of $E - \hbar\omega_{LO} = 14$ meV. A crossing between the $n = 2$ initial-state line and the $n = 0$ final-state line occurs around $B = 10.3$ T (circled). At this point the momentum of the electron in the transport direction is conserved by the scattering and this gives rise to the enhanced rate observed in the main panel. Parameters the same as Fig. 1.

The dependence on $n' - n$ here means that for large fields, the inwards off-diagonal transitions, $n' > n$, are increasingly more suppressed than the diagonal ones. Thus starting in the outermost channel, the $n = 0$ to $n' = 0$ transition will dominate at high field. For $\Omega \lesssim \omega_{LO}$, however, rates other than the diagonal ones will contribute.

The total scattering rate out of state n is simply the sum $\Gamma_n(E) = \sum_{n'} \Gamma_{n'n}(E)$. Results for $n = 0$, using both the exact integral $I_{n'0}$ and the approximate form of Eq. (10), are shown in Fig. 1. This figure shows that the rate exhibits an approximately exponential drop across most of the experimentally accessible magnetic-field range and that Eq. (10) provides a decent account of this behavior. The inset of Fig. 1 shows the total rate at low fields. We see that the decay rate has a maximum value in the range $5 - 10$ ps $^{-1}$ and occurs for $B > 0$. The rate at low fields also exhibits a series of peaks as a function B that arise from the density of states factor, $\Delta_{n'}^{-1/2}$, in Eq. (8). At these points, Eq. (6) does not hold and the closed parabola is no longer an accurate model of the experimental potential. Missing from the current description are the bulk states that occur in the flat region of the potential. Due to the magnetic field, however, these additional states will be dispersionless and the spectrum of the open-parabola system will still consist of a set of distinct subbands. Thus, even though the positions and strengths of these peaks will be modified in the open potential, the essential ingredient behind this behavior remains.

We thus expect the behavior described here to be qualitatively similar to that observable in experiment.

Figure 2 shows the total scattering rate out of states other than the $n = 0$ level. Generically, these rates show a behavior similar to the $n = 0$ case. In certain circumstances, however, these rates can attain anomalously high values; see, e.g., the $n = 2$ result in Fig. 2 around $B = 10$ T. These features occur whenever initial-state and final-state lines cross in a plot of wave number versus field (see the inset of Fig. 2). At these points, the momentum of the electron in the x direction is conserved and, from the inverse dependence of the electron-phonon matrix element on the phonon momentum [see Eq. (B2)], this gives rise to enhancement in the scattering rate.

IV. ARRIVAL-TIME DISTRIBUTION

We now consider the time of arrival of electrons at a detector situated at a position x_D from the emitter along the edge channel. Since there is some uncertainty in the time of emission [8], we define the arrival-time distribution as the distribution of times at which an electron is detected at x_D measured relative to some fixed time, which we here take as the onset of the emission process. This definition corresponds well to the experimental situation of Refs. [7,8]. Note that this distribution includes uncertainty stemming from both the emission process as well as from the subsequent evolution of the electronic states.

Let us denote as $A^{(m)}(x_D, \tau)$ the distribution of arrival times of electrons having emitted exactly m phonons en route to the detector. The adjustable barrier height of the detectors in Refs. [7,8], together with the comparatively large separation in energy of the distributions for different m , means that these individual phonon-replica distributions should be observable in experiment. The normalization of $A^{(m)}$ is such that $P^{(m)}(x_D) \equiv \int_0^\infty d\tau A^{(m)}(x_D, \tau)$ is the total probability of m phonons being emitted *en route* and $\sum_{m=0} P^{(m)}(x_D) = 1$. For each value of m , we define the mean arrival time

$$\langle \tau^{(m)} \rangle \equiv \frac{\int_0^\infty d\tau \tau A^{(m)}(x_D, \tau)}{P^{(m)}(x_D)}, \quad (14)$$

and width

$$\Delta \tau^{(m)} \equiv \sqrt{\frac{\int_0^\infty d\tau [\tau^2 - \langle \tau^{(m)} \rangle^2] A^{(m)}(x_D, \tau)}{P^{(m)}(x_D)}}. \quad (15)$$

To calculate the ATDs, we should consider that the electron is emitted as a wave packet with a range of k values. In principle, this affects the time evolution of the electron not only through the dispersion of Eq. (4), but also through the energy (and hence wave number) dependence of the scattering rate. A quantum-mechanical treatment of the ATD that addresses these issues is discussed in Appendix C. In this treatment, we assume that the initial spatial distribution of the electron is a Gaussian wave packet with a spatial extent $\gtrsim 1 \mu\text{m}$, which is a reasonable assumption for the situation described in Refs. [7,8]. In this case, we find that the relative spread in wave number k is small enough that the dispersion of the wave packet can be neglected over relevant source-detector distances. The variation of the phonon rates, the guide-center positions, and the velocities over the relevant k range are also

negligibly small. In the following, then, we neglect dispersion and employ a semiclassical description of the dynamics. We note that were the initial extent of the wave packet to be $\lesssim 100$ nm, we would expect k -dependent effects to become significant.

A. Semiclassical dynamics

Let us denote as $\varrho_n^{(m)}(x, t)$ the classical probability distribution to find at time t an electron at position x of edge channel n given that it has emitted m phonons. In a semiclassical picture, we consider an electron in edge channel n to have a well-defined energy and velocity, irrespective of its spatial distribution. We can thus unambiguously associate with the m -phonon distribution an energy $E^{(m)} = E^{(0)} - m\hbar\omega_{\text{LO}}$, where $E^{(0)}$ is the initial energy at emission. We then label quantities with the phonon number m as a proxy for the energy and thus write $v_n^{(m)}$ for the velocity of the electron in the n th subband with energy $E^{(m)}$. We label the rates with the m value of the starting state, rather than the energy: $\Gamma_{n'n}^{(m)} = \Gamma_{n'n}(E^{(m)})$.

For the probabilities, we write down a set of coupled Boltzmann-like equations with drift and scattering terms,

$$\begin{aligned} \frac{\partial}{\partial t} \varrho_n^{(m)} + v_n^{(m)} \frac{\partial}{\partial x} \varrho_n^{(m)} \\ = -(1 - \delta_{m,M}) \Gamma_n^{(m)} \varrho_n^{(m)} + (1 - \delta_{m,0}) \sum_{n'} \Gamma_{nn'}^{(m-1)} \varrho_{n'}^{(m-1)}. \end{aligned} \quad (16)$$

Here M is the maximum number of phonons that an electron can emit before its energy falls to less than $\hbar\omega_{\text{LO}}$ above the bottom of the $n = 0$ subband, from which point no further emission is possible. In terms of these probabilities, the ATD at energy $E^{(m)}$ is simply related to the current as [35]

$$\begin{aligned} A^{(m)}(x_D, \tau) &= \sum_n A_n^{(m)}(x_D, \tau) \\ &= \sum_n v_n^{(m)} \varrho_n^{(m)}(x_D, t = \tau). \end{aligned} \quad (17)$$

In the first line here we have written $A^{(m)}$ as a sum over the contributions from the individual edge channels, $A_n^{(m)}$.

B. Survival probability

The first quantity in which we are interested is the survival probability, $P^{(0)}(x_D, \tau)$, which is the probability that the electron reaches the detector without emitting any phonons. We assume that the electron is emitted into the outermost edge channel with a starting probability density $\varrho_0^{(0)}(x, 0) = f(x)$. The solution of Eq. (16) with $m = n = 0$ gives simply

$$\varrho_0^{(0)}(x, t) = e^{-\Gamma_0^{(0)} t} f(x - v_0^{(0)} t), \quad (18)$$

which represents a wave packet traveling with velocity $v_0^{(0)}$, damped at a rate $\Gamma_0^{(0)}$. We assume that the initial distribution is a Gaussian of spatial width σ and central coordinate x_0 . In Ref. [8], it was determined that the electron wave packet was emitted over some fixed time interval $\Delta \tau_i$. This gives the initial width of the wave packet to be $\sigma = v_0^{(0)} \Delta \tau_i$. Since the wave packet begins to form at $t = 0$, we set the central coordinate

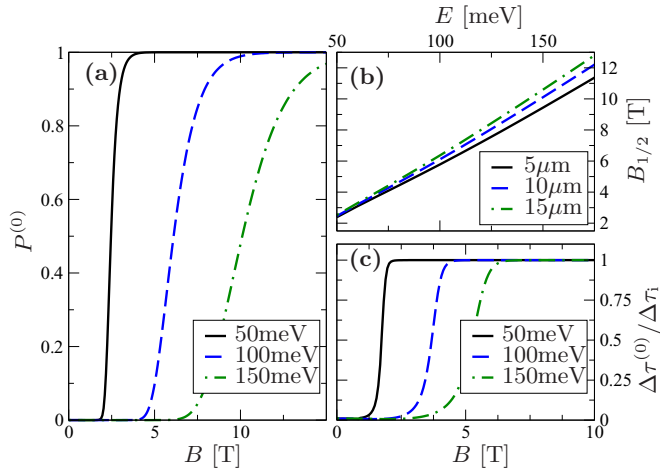


FIG. 3. (a) The survival probability, $P^{(0)}$, for electrons to reach a detector at $x_D = 10$ μm without emitting a phonon for initial energies $E^{(0)} = 50, 100, 150$ meV. A rapid transition from zero to unity is observed in the experimentally relevant range of magnetic fields. (b) The field value $B_{1/2}$ at which the survival probability reaches one-half as a function of initial energy E . Results are shown for $x_D = 5, 10, 15$ μm. (c) The width of the $m = 0$ arrival-time distribution, $\Delta\tau^{(0)}$, in units of the initial width $\Delta\tau_i$ [same energies and detector position as (a)]. Above $B_{1/2}$, the width plateaus to its value at emission. Parameters the same as Fig. 1.

$x_0 = -2\sigma$ such that $\varrho_0(x \geq 0, 0) \approx 0$ for $x \geq 0$. Reference [8] describes 30 ps as an overestimate of width, and we shall take 20 ps in our numerical calculations. By integrating Eq. (18) with this Gaussian ansatz, we find a survival probability

$$P^{(0)}(x_D) = \frac{1}{2} \exp \left\{ -\frac{\Gamma_0^{(0)}(x_D - x_0)}{v_0^{(0)}} + \frac{1}{2} \left(\frac{\sigma \Gamma_0^{(0)}}{v_0^{(0)}} \right)^2 \right\} \times \operatorname{erfc} \left\{ \frac{\sigma^2 \Gamma_0^{(0)} - v_0^{(0)}(x_D - x_0)}{\sqrt{2} \sigma v_0^{(0)}} \right\}. \quad (19)$$

This result is shown in Fig. 3(a) with rates and velocities calculated as in the preceding sections. We see that the survival probability undergoes a rapid transition from close to zero for low fields to close to unity for high field. In the limit $(x_D - x_0)/\sigma \gg 1, \sigma \Gamma_0^{(0)}/v_0^{(0)}$, the degree of scattering experienced by the wave packet as it passes the point x_D is negligible, and we find

$$P^{(0)}(x_D) \approx \exp \left\{ -\frac{\Gamma_0^{(0)}(x_D - x_0)}{v_0^{(0)}} \right\}, \quad (20)$$

which represents a simple exponential decay in time evaluated at the mean-time of arrival at the detector. Since, for large B at least, the rate $\Gamma_0^{(0)}$ behaves as in Eq. (11), the result of Eq. (20) is a *double-exponential* suppression on the survival probability as the magnetic field decreases. From Eq. (11) we also see that the magnetic field at which the survival probability reaches one-half, $B_{1/2}$, is roughly proportional to B_T . Complete results for this crossover field are shown in Fig. 3(b) as a function of energy. We note that at low field, the rate $\Gamma_0^{(0)}$ is high enough

that the wave packet is almost entirely suppressed before it can reach the detector. In this case, Eq. (20) ceases to be a good approximation. Rather, in the limit $\sigma \Gamma_0^{(0)}/v_0^{(0)} \gg 1$, $(x_D - x_0)/\sigma$, we obtain

$$P^{(0)}(x_D) \approx \frac{v_0^{(0)}}{\Gamma_0^{(0)}} f(x_D), \quad (21)$$

such that only the exponentially small tail of the distribution contributes in this limit.

C. Distribution widths

We now consider the complete ATDs and characterize them in terms of their widths. Considering first the $m = 0$ case, the same approximations that lead to Eq. (20), give the width of the $m = 0$ ATD to be

$$\Delta\tau^{(0)} = \frac{\sigma}{v_0^{(0)}}, \quad (22)$$

which is simply the typical time it takes for a wave packet of width σ to move across the detector. In the emission model such that $\sigma = v_0^{(0)} \Delta\tau_i$, we obtain $\Delta\tau^{(0)} = \Delta\tau_i$ and the width of this distribution remains constant irrespective of the decay process. This behavior is observed at high fields in Fig. 3(c), but as B decreases through the transition point $B_{1/2}$, the width of the arrival-time distribution drops. This reduction in width occurs because different parts of the electron distribution experience different total losses en route to the detector. Parts further away suffer the greatest and this narrows the final detected distribution. We note that the fixity of the temporal width relies on the assumption that the electron is emitted over a constant time window irrespective of other conditions. If, for example, it were the initial spatial width σ , rather than the temporal width, that was fixed, then $\Delta\tau^{(0)}$ would show an approximately linear increase with field.

We next consider the distributions for $m > 0$. Results from the numerical solution of Eq. (16) are shown in Fig. 4 for $B = 5$ T and in Fig. 5 for $B = 2$ T. We start by discussing Fig. 4, as these results are indicative of what happens at higher field. Starting at low energy, the ATD for $m = 0$ shows a strong peak given by Eq. (18). As the initial energy of the electron increases, this peak moves to shorter times as the velocity increases in line with Eq. (5). At around $E^{(0)} = \frac{1}{2} \hbar \Omega + \hbar \omega_{LO} \approx 80$ meV, scattering out of this state becomes significant and population transfers to the $m = 1$ state. This continues until about $E^{(0)} = \frac{1}{2} \hbar \Omega + 2 \hbar \omega_{LO} \approx 115$ meV, at which point the emission of two phonons becomes likely and the $m = 2$ distribution develops. The temporal widths of the distributions increase with increasing m , but narrow throughout their individual ranges as $E^{(0)}$ increases. The distributions here are largely featureless.

A similar story unfolds at lower fields, Fig. 5, but the increase in width with m here is more marked. Moreover, a distinct structure evolves in the $m > 0$ distributions. While the transition from $m = 0$ to $m = 1$ distribution is gradual, the $m = 1$ distribution undergoes an abrupt cutoff around $E = \frac{1}{2} \hbar \Omega + 2 \hbar \omega_{LO} \approx 74$ meV. The $m = 2$ distribution that then arises shows a series of bands with increasing energy in which the width of the distribution oscillates. The $m = 1$

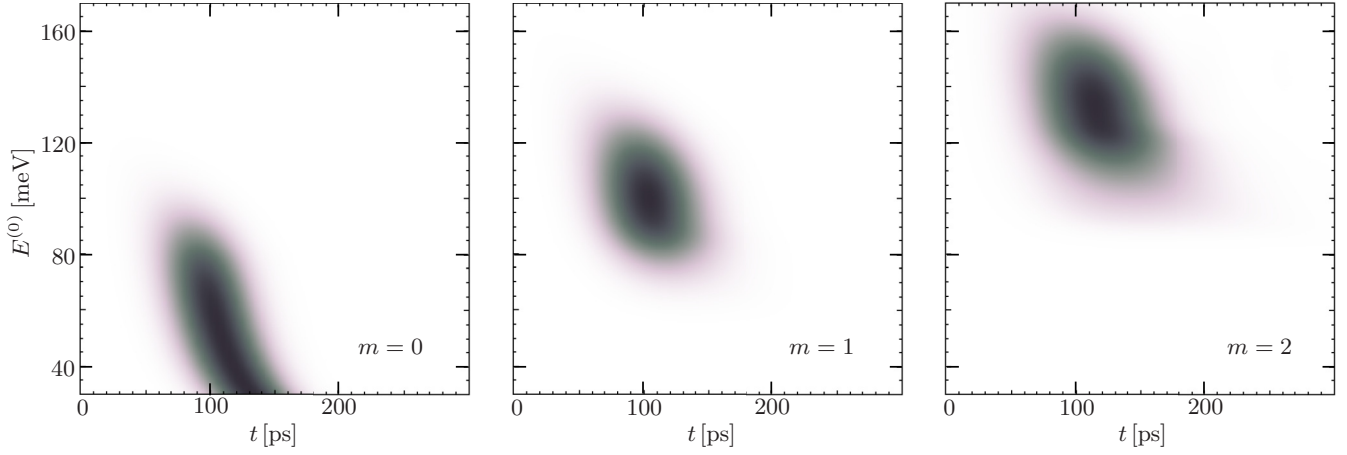


FIG. 4. Arrival-time distributions as function of time t and initial electron energy $E^{(0)}$. The three panels show the distributions detected at energies $E^{(m)}$ with $m = 0, 1, 2$, i.e., with the electron having emitted $m = 0, 1, 2$ phonons. Here $B = 5$ T, $x_D = 10$ μm , and the initial width was $\Delta\tau_i = 20$ ps. As the initial energy increases, the distribution first moves from $m = 0$ to $m = 1$ as the one-phonon emission process becomes possible. Then, with further increase in energy, two-phonon emission becomes possible and the distribution moves to $m = 2$.

distribution shows this oscillation too, but less obviously than for $m = 2$.

To help understand these results, we consider the case when the maximum number of phonons that can be emitted is $M = 1$. This occurs when $\frac{1}{2}\hbar\Omega + \hbar\omega_{LO} \leq E^{(0)} < \frac{1}{2}\hbar\Omega + 2\hbar\omega_{LO}$. In this case, Eq. (16) can be solved exactly. With Gaussian initial conditions, the one-phonon distribution for subband n reads

$$A_n^{(1)}(x, t) = \frac{\Gamma_{n0}^{(0)} v_n^{(1)}}{2(v_0^{(0)} - v_n^{(1)})} \left\{ e^{-\Gamma_0^{(0)} t} f(x - v_0^{(0)} t) C(z_2) - f(x - v_n^{(1)} t) C(z_1) \right\}, \quad (23)$$

with $C(z) = \exp(z^2) \text{erfc}(z)$ and

$$z_1 = \frac{\sigma^2 \Gamma_0^{(0)} - (v_0^{(0)} - v_n^{(1)})(x - v_0^{(0)} t)}{\sqrt{2}\sigma(v_0^{(0)} - v_n^{(1)})}, \quad (24)$$

$$z_2 = \frac{\sigma^2 \Gamma_0^{(0)} - (v_0^{(0)} - v_n^{(1)})(x - v_n^{(1)} t)}{\sqrt{2}\sigma(v_0^{(0)} - v_n^{(1)})}.$$

Taking the limit $\Gamma_0^{(0)} t \gg 1$, and approximating $C(z) \approx 1/(\sqrt{\pi}z)$ [36], we obtain

$$A_n^{(1)}(x, t) \approx \frac{\Gamma_{n0}^{(0)}}{\Gamma_0^{(0)}} f(x - v_n^{(1)} t). \quad (25)$$

The width of this distribution for edge channel n is

$$\Delta\tau_n^{(1)} \approx \Delta\tau_i \frac{v_0^{(0)}}{v_n^{(1)}}. \quad (26)$$

Thus, we expect the complete $m = 1$ ATD to be approximately given by a sum of Gaussians with center and widths determined by the velocity ratios $v_0^{(0)}/v_n^{(1)}$ and weighted by the branching ratio $\Gamma_{n0}^{(0)}/\Gamma_0^{(0)}$.

Figure 6 shows the total widths $\Delta\tau^{(m)}$ of the distributions in Figs. 4 and 5 in comparison with the partial widths,

$$\Delta\tau_n^{(m)} \approx \Delta\tau_i \frac{v_0^{(0)}}{v_n^{(m)}}, \quad (27)$$

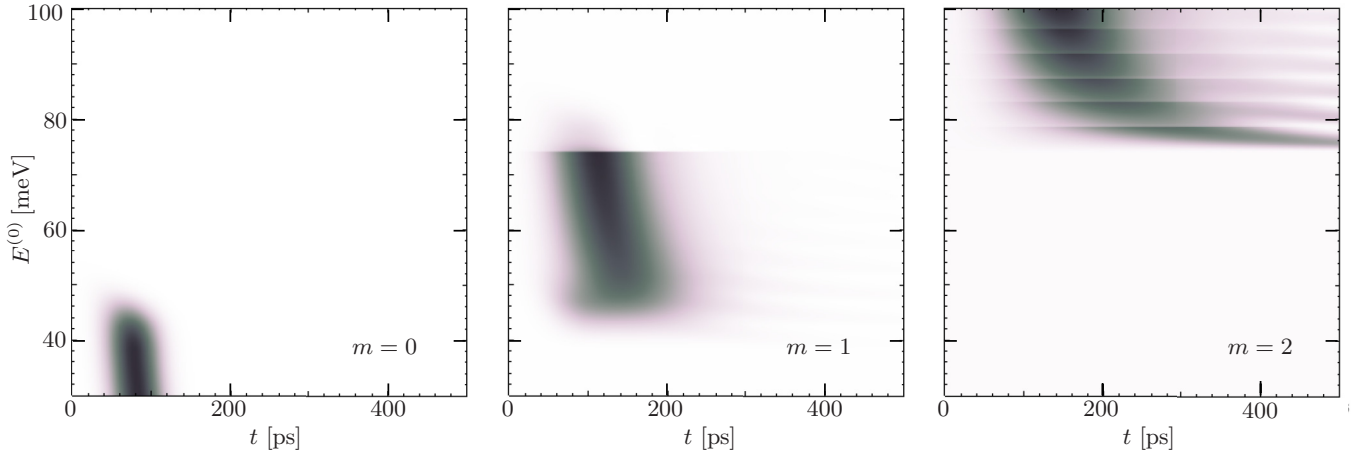


FIG. 5. Same as Fig. 4 but with $B = 2$ T. The transitions here between the distributions with different m are more abrupt. Furthermore, the distributions develop oscillations in their widths as a function of initial energy.

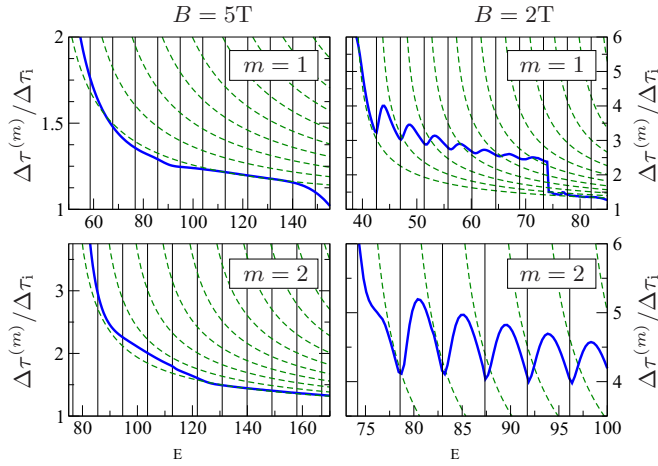


FIG. 6. Widths $\Delta\tau^{(m)}$ of the arrival-time distributions for $m = 1$ (top row) and $m = 2$ (bottom) as a function of initial energy $E^{(0)}$ for two values of the magnetic field $B = 5$ T (left) and $B = 2$ T (right). The thick lines show the widths of the distributions; the green dashed lines show the partial widths $\Delta\tau_n^{(m)}$ predicted by Eq. (27); the black vertical lines show the (initial) energies for which $E^{(m)}$ is equal to a subband-bottom energy, i.e., when $E^{(0)} = m\hbar\omega_{LO} + \hbar\Omega(n + \frac{1}{2})$. In all four panels, the leftmost partial width is that for $n = 0$, with n increasing in steps of 1 from left to right. At $B = 5$ T, the total width is determined almost exclusively by the properties of the outermost edge channel. At $B = 2$ T, the width shows oscillations with increasing field arising from the contribution of a succession of different subbands.

generalized from Eq. (26). For $B = 5$ T, the situation is rather simple: across most of the energy range considered here, the full width decreases with E and corresponds very closely to the $n = 0$ partial width. This is indicative of the fact that, for these parameters, scattering is dominated by the $n = 0 \rightarrow n' = 0$ transition. At higher energies, the width decreases below this level. This effect has the same origin as the reduction discussed in connection with Fig. 3(c).

The distribution widths for $B = 2$ T show oscillations as a function of energy. Analogously to the Shubnikov–de Haas oscillations, these occur as the relevant energy, here $E^{(m)}$, passes through the band-bottom energies. Consider first the $m = 1$ case. Below $E^{(0)} = \frac{3}{2}\hbar\Omega + \hbar\omega_{LO} \approx 42.5$ meV the only available state into which the electron can scatter is the outermost edge channel. The width of distribution therefore follows $\Delta\tau_0^{(1)}$. At $E^{(0)} \approx 42.5$ meV, the band bottom of the $n = 1$ state passes through the energy $E^{(1)}$ and scattering into this state becomes possible. Initially the rate of this process is small, but as energy increases, an increasing fraction of population is scattered into this state. As the velocity of this $n = 1$ state is significantly lower than that of the $n = 0$ state, the width of its partial distribution is greater. Thus, as more population is added to this state, the width of the distribution comes to be dominated by this wider contribution. Above a certain point the total width of the $m = 1$ distribution follows roughly the $n = 1$ partial width. At $E^{(0)} = \frac{5}{2}\hbar\Omega + \hbar\omega_{LO} \approx 47$ meV, the same thing occurs with the $n = 2$ subband, which then determines the total width. This pattern continues with increasing $E^{(0)}$. At higher energies, however, the total

distribution is actually a mixture of contributions from all the states with subbands below $E^{(1)}$. These different contributions combine to make the alignment of the oscillation minima drift away from the exact subband energies.

The $m = 1$ width shows a sharp drop to the width of the $\Delta\tau_0^{(1)}$ level at $E^{(0)} = \frac{1}{2}\hbar\Omega + 2\hbar\omega_{LO} \approx 74$ meV. This corresponds to the transition in the maximum phonon number from $M = 1$ to $M = 2$ when two-phonon processes become possible. In accordance with Fig. 2, the rates out of the $n > 0$ states are greater than those from the $n = 0$ states. Thus, at these energies, any residual population in $m = 1$ distribution will predominantly be in the $n = 0$ state. At the onset of the $m = 2$ distribution, its width starts below $\Delta\tau_0^{(2)}$. This is a result of the admixture of components traveling with velocities from the source level (here $m = 1$), just as Eq. (23) shows that the $m = 1$ distribution contains an admixture of slower $m = 0$ velocity components.

Due to the passing of the electron energy through subband bottoms, the prediction of this effect for experiment can be only qualitative, rather than quantitative. Certainly near the bottom of the bands, the shape of the partial width curves will change from those shown here, since the dispersion relation will be modified. However, when $E^{(m)}$ is near a subband bottom, the width is actually determined by the width of the next-lowest band, for which our electronic states should be a good approximation. By the time the energy is increased enough to follow the partial width curve of a subband, the energy is already significantly higher than the band bottom. The width oscillations should therefore show a similar pattern in the open-parabola potential.

V. DISCUSSION

The advent of single-electron sources coupled with energy- and time-resolved detection opens new possibilities to study confined electron-phonon interactions in detail [7,8]. Here, we have calculated relaxation rates due to LO-phonon emission in quantum Hall edge channels and studied the consequences of these processes for the arrival-time distributions of electrons at a downstream detector. The rates show an exponential suppression with increasing field strength as the electronic wave functions become more localized. This, in turn, translates into a double-exponential suppression of the survival probability as the field decreases. These calculations explain the observations of phonon-scattering suppression at high magnetic fields in Refs. [7,8]. More quantitatively, Ref. [7] reports an electron emission energy of 150 meV above the Fermi sea. Taking this to coincide with the energy above the potential bottom, our calculations suggest that the magnetic field at which the survival probability drops to one-half is $B_{1/2} \approx 9$ T for a detector at $x_D = 3 \mu\text{m}$. This is consistent with the strong phonon scattering at $B = 6$ T and its almost complete absence at $B = 12$ T as observed in Ref. [7].

For scattering out of the higher $n > 0$ edge channels, our rates show an anomalously high value whenever the transition is vertical in the electron forward momentum. In the experiments of Refs. [7,8], it is believed that the electrons are emitted only into the $n = 0$ level. To observe these anomalously high rates then, it is necessary to scatter electrons into these higher states post emission. Phonon emission cannot

provide this scattering because, looking at Fig. 2, the crossing occurs at high field where scattering from the $n = 0$ channel is both highly suppressed as well as effectively diagonal in the subband index. To observe these rates an additional scattering process, such as at a quantum point contact to populate inner edge channels, is required.

Concerning the ATDs themselves, we predict here an increase in the width of the phonon-replica distributions relative to that of the direct distribution. Since this change in width depends on the change in the k value of the electron during phonon emission, at high energy, where the relative proportion of energy lost is small, the width increase will be correspondingly small. However, at lower energy and field, this width increase can be significant. In Fig. 6, for example, the width of the $B = 2$ T distribution around their midpoint in energy range is a factor of 3 ($m = 1$) or 5 ($m = 2$) greater than the starting width. Such increases should be visible with the time-domain resolution reported in Ref. [7] and might prove a useful way to characterize the resolution of the detector. We have also seen that, at lower field, the distributions exhibit an oscillatory behavior due to subband crossings. The width of the distribution where these oscillations occur is significantly greater than the original emission width and should therefore be resolvable in current experiment.

In this work, we have employed a single-electron description that neglects the interaction of the injected electrons with the two-dimensional electron gas resident in the device. This follows from the fact that, in the charge-pump experiments in question, electrons are emitted at an energy that is high relative to the Fermi level. With an injection energy around 100 meV, the propagation path of the electrons lies spatially well outside the electron gas—the distance between the electron path and electron gas is of the order of 100 nm, which is much greater than the magnetic length of ~ 10 nm at 10 T. The effects of interactions between the injected electrons and the electron gas are thus much reduced. Indeed, in Ref. [22], the scattering length due to these interactions is estimated to be about $5 \mu\text{m}$ for a hot electron of 100 meV and at the field of 10 T, based on an electron gas confined in a hard wall potential; in a more realistic situation of a relatively smooth confinement, the scattering length could be longer. Electron-electron interaction effects can be yet further suppressed by the use of top gates to deplete the electron gas in the region close to the propagation path [28]. We note however, that the interaction effects will increase after the energy of the injected electron has been reduced by multiple phonon emissions.

There are a number of ways in which our phonon calculations could be extended. First, the description of states near the subband bottoms could be brought closer to those in experiment by considering the open-parabola potential. While this should give better agreement with experiment in specific parameter regions, some of the simplicity of the above approach will inevitably be lost. More interesting will be to include further effects relating to the phonons. In particular, confinement of the optical phonons has been reported to be important in nanostructures in magnetic fields [31] and this is not included in the current calculation. The influence of acoustic phonons on edge-state dynamics [37] has also not been considered here. Finally, it will be of interest to go beyond the Fermi-golden-rule approach used here and

look for signatures of polaron physics in the single-electron arrival-time distributions.

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APPENDIX A: QUANTUM HALL WAVE FUNCTIONS

The eigenfunctions of the Hamiltonian of Eq. (1) are

$$\psi_{nk}(x, y) = \frac{1}{\sqrt{L_x l_\Omega}} e^{ikx} u_n\left(\frac{y - y_G}{l_\Omega}\right), \quad (\text{A1})$$

where normalization in the x direction is to the length of the conductor L_x , and where

$$u_n(s) = \frac{1}{\sqrt{2^n n!}} \frac{1}{\pi^{1/4}} e^{-s^2/2} H_n(s), \quad (\text{A2})$$

are the standard harmonic-oscillator functions with $H_n(s)$ the n th Hermite polynomial.

To calculate the interaction with bulk phonons, we supplement this wave function with that in the growth direction z . Assuming the confinement in this direction to be an infinite square well with boundaries at $z = 0$ and $z = a$, the ground-state wave function in this direction is

$$\phi_1(z) = \begin{cases} \sqrt{\frac{2}{a}} \sin \frac{\pi z}{a} & \text{for } 0 \leq z \leq a; \\ 0 & \text{otherwise.} \end{cases} \quad (\text{A3})$$

We assume that the energy of excitation in this z direction is large enough that the electron is confined to this ground state. The total wave function used in the calculation of matrix elements is then

$$\Psi_{nk}(x, y, z) = \psi_{nk}(x, y) \phi_1(z). \quad (\text{A4})$$

APPENDIX B: CALCULATION OF ELECTRON-PHONON RATES

Specified in terms of $\tilde{c}_{\mathbf{k}}$, the annihilation operator for plane-wave electrons with three-dimensional wave vector \mathbf{k} , the Fröhlich Hamiltonian for polar optical phonons reads [24]

$$V_{\text{ep}} = \sum_{\mathbf{k}, \mathbf{q}} M(\mathbf{q}) \tilde{c}_{\mathbf{k}+\mathbf{q}}^\dagger \tilde{c}_{\mathbf{k}} (a_{-\mathbf{q}}^\dagger + a_{\mathbf{q}}), \quad (\text{B1})$$

with matrix element

$$M(\mathbf{q}) \equiv \frac{M_0}{\sqrt{V}} \frac{1}{|\mathbf{q}|}; \quad M_0^2 = 4\pi\alpha\hbar \frac{(\hbar\omega_{\text{LO}})^{3/2}}{(2m_e^*)^{1/2}}. \quad (\text{B2})$$

Translating into the basis of Eq. (A4), we obtain Eq. (7) with the matrix elements [38]

$$\begin{aligned} \Lambda_{n'n}^{k'k}(\mathbf{q}) &= \sum_{\mathbf{p}} M(\mathbf{q}) \langle \Psi_{n'k'} | \mathbf{p} + \mathbf{q} \rangle \langle \mathbf{p} | \Psi_{nk} \rangle, \\ &= M(\mathbf{q}) \delta_{q_x, k' - k} G_{n'k', nk}^{(y)}(q_y) G_{11}^{(z)}(q_z), \end{aligned} \quad (\text{B3})$$

with

$$G_{n'nk}^{(y)}(q_y) = l_\Omega^{-1} e^{-iq_y y_G} \int dy e^{iq_y y} u_{n'}^*(l_\Omega^{-1} y) u_n^*(l_\Omega^{-1} y);$$

$$G_{11}^{(z)}(q_z) = \int dz e^{iq_z z} \phi_1^*(z) \phi_1(z). \quad (\text{B4})$$

Fermi's golden rule then gives the transition rate from state n with energy E to state with n' as

$$\Gamma_{n'n}(E) = \frac{L_x}{\hbar} \int dk' \sum_{\mathbf{q}} |\Lambda_{n'n}^{k'k}(\mathbf{q})|^2 \delta(E_{n'k'} - E + \hbar\omega_{\text{LO}}). \quad (\text{B5})$$

Taking the continuum limit for \mathbf{q} , three of the four integrals in this expression can be evaluated analytically [34]. This yields Eq. (8) with the remaining integral

$$I_{n'n}(\delta_G) = \int dQ F_{11}^{(z)} \left(\sqrt{Q^2 + \left(\frac{a\Omega}{l_\Omega \omega_c} \right)^2 \delta_G^2} \right) \times F_{n'n}^{(y)} \left(\sqrt{\frac{1}{2} \left[\frac{l_\Omega^2}{a^2} Q^2 + \delta_G^2 \right]} \right). \quad (\text{B6})$$

Here we have defined

$$F_{11}^{(z)}(A) \equiv \int dQ \frac{1}{A^2 + Q^2} |G_{11}^{(z)}(Q/a)|^2, \quad (\text{B7})$$

which evaluates as

$$F_{11}^{(z)}(A) = \frac{3\pi A^5 + 20\pi^3 A^3 - 32\pi^5(1 - e^{-A})}{A^3(A^2 + 4\pi^2)^2}, \quad (\text{B8})$$

and we have written

$$|G_{n'nk}^{(y)}(q_y)|^2 = F_{n'n}^{(y)} \left(\sqrt{\frac{1}{2} [l_\Omega^2 q_y^2 + \delta_G^2]} \right), \quad (\text{B9})$$

with

$$F_{n'n}^{(y)}(Q) = \frac{n_{<}!}{n_{>}!} e^{-Q^2} Q^{2|n'-n|} [L_{n_{<}}^{n'-n}(Q^2)]^2. \quad (\text{B10})$$

In this latter, $L_n^\alpha(x)$ is an associated Laguerre polynomial and $n_{<} = \min(n_2, n_1)$ and $n_{>} = \max(n_2, n_1)$. In writing Eq. (B6), we have neglected processes which change the sign of k . This is consistent with only one side of the potential being relevant to the experimental potential. Processes that change the sign of \mathbf{k} will anyway be severely suppressed when $y_G \gg l_\Omega$.

The approximation to $I_{n'0}$ given in Eq. (10) can be obtained by noting that the exponential factor in $F^{(y)}$ dominates the integrand. Setting $Q = 0$ everywhere but in this exponent, we obtain

$$I_{n'n}(\delta_G) \approx \int dQ e^{-\frac{1}{2} \left(\frac{l_\Omega Q}{a} \right)^2} F_{11}^{(z)} \left(\frac{a\Omega}{l_\Omega \omega_c} \delta_G \right) F_{n'n}^{(y)} \left(\frac{1}{\sqrt{2}} \delta_G \right) = \frac{\sqrt{2\pi} a}{l_\Omega} F_{11}^{(z)} \left(\frac{a\Omega}{l_\Omega \omega_c} \delta_G \right) F_{n'n}^{(y)}. \quad (\text{B11})$$

Further, if the initial energy of the electron E is the dominant energy scale, we can approximate

$$\delta_G \approx \frac{\omega_c^2 \omega_{\text{LO}}}{\omega_y^2 \Omega} \frac{l_\Omega}{y_G}. \quad (\text{B12})$$

This gives $\delta_G \sim E^{-1/2}$ and we thus expand the nonexponential contribution for small δ_G to obtain Eq. (10).

APPENDIX C: QUANTUM DYNAMICS

We can assess the importance of dispersion by considering the time evolution of a Gaussian wave packet [39,40]. We assume that initially the electron is confined to the lowest Landau level ($n = 0$) with momentum distributed normally. The wave function then reads

$$|\Psi(0)\rangle = \sum_k N_\alpha e^{-\alpha(k-k_0)^2} |\psi_{0k}\rangle, \quad (\text{C1})$$

with k_0 the central wave number and $\alpha = \sigma^2$ a width parameter with $k_0 \gg (4\alpha)^{-1/2}$, such that only positive values of k are relevant. N_α is a normalization constant. The marginal probability distribution of this state in the x direction is a Gaussian with width

$$\sqrt{v} = \sqrt{\alpha + \frac{1}{2} \left(\frac{\omega_c}{\Omega} l_\Omega \right)^2}. \quad (\text{C2})$$

The increase over $\sqrt{\alpha} = \sigma$ stems from the dependence on wave number of the guiding center of the transverse wave function.

The time evolution of this wave packet including phonon-induced relaxation can be found by solving the time-dependent Schrödinger equation with eigenenergies that have imaginary parts to account for the population decay. The wave function at later time t is then

$$|\Psi(t)\rangle = \sum_k N_\alpha e^{-\alpha(k-k_0)^2 - i\hbar^{-1} \tilde{E}_{0k} t} |0, k\rangle, \quad (\text{C3})$$

with $\tilde{E}_{0k} = E_{0k} - i\frac{\hbar}{2} \Gamma_0^k$ where, for the purposes of this appendix, we have labeled the rate with the initial wave number: $\Gamma_0^k = \Gamma_0(E_{0k})$. At high energy and field, the rate is a slowly varying function of k . We therefore approximate $\Gamma_0^k \approx \Gamma_0^{k_0} + \partial_k \Gamma_0^{k_0} [k - k_0] + \frac{1}{2} \partial_k^2 \Gamma_0^{k_0} [k - k_0]^2$.

The simplest way to define an arrival time distribution in quantum mechanics is in relation to the current density [41,42],

$$A(x_D, t) \equiv \int dy \mathbf{J}(x_D, y, t) \cdot \hat{\mathbf{i}}, \quad (\text{C4})$$

where $\mathbf{J}(x, y, t)$ here is given by

$$\mathbf{J}(x, y, t) = \frac{1}{m_e^*} \text{Re} \left\{ \Psi^*(x, y, t) \left(\mathbf{p} + \frac{e}{c} \mathbf{A} \right) \Psi(x, y, t) \right\}. \quad (\text{C5})$$

This definition can lead to problems of interpretation [35,43] but under the conditions studied here, no such issues arise. With the wave function of Eq. (C3), we obtain

$$A(x_D, t) = \frac{1}{\sqrt{2\pi} \tilde{v}} D^{-3/2} \tilde{v}_g \left[1 + (D-1) \frac{x_D}{\tilde{v}_g t} \right] \times \exp \left[-\frac{1}{2\tilde{v} D} (x_D - \tilde{v}_g t)^2 \right] \sqrt{\frac{\alpha}{\tilde{\alpha}}} \exp[-\tilde{\Gamma} t], \quad (\text{C6})$$

with

$$\begin{aligned}\tilde{\alpha} &= \alpha + \frac{1}{4}(\partial_k^2 \Gamma_0^{k_0})t; & \tilde{\nu} &= \tilde{\alpha} + \frac{1}{2}\left(\frac{\omega_c}{\Omega}\right)^2 l_c^2; \\ D &= 1 + \frac{\hbar^2 t^2}{4m_e^* \tilde{\alpha} \tilde{\nu}}; & \tilde{v}_g &= v_g - (\partial_k \Gamma_0^{k_0}) \frac{\hbar t}{4m_e^* \tilde{\alpha}}; \\ \tilde{\Gamma} &= \Gamma_0^{k_0} + (\partial_k \Gamma_0^{k_0})^2 \frac{t}{8\tilde{\alpha}}.\end{aligned}\quad (C7)$$

This can be understood as the ATD of a damped, traveling Gaussian wave packet moving with velocity, width, and damping rate that are all functions of time.

We can assess the importance of the time dependence of these parameters for experiment. By assuming $t \sim x_D/v_g$, a width parameter $\alpha \approx (1 \mu\text{m})^2$ and detector position $x_D = 10 \mu\text{m}$, we numerically obtain a value of $\tilde{\alpha}/\alpha - 1 \approx 10^{-5}$ for $B = 5 \text{ T}$ and $E = 100 \text{ meV}$, which is a typical value in the relevant parameter range. A similar story can be told for the corrections involving the derivatives of the rates—these terms yield relative corrections of the order of 10^{-5} or less. We are thus safe in approximating $\tilde{\alpha} \approx \alpha$, $\tilde{\nu} \approx \nu$, $\tilde{\Gamma} \approx \Gamma_0^{k_0}$, and $\tilde{v}_g \approx v_g$.

Concerning the width adjustment, we have

$$\frac{\tilde{\nu}}{\tilde{\alpha}} - 1 \approx \frac{\nu}{\alpha} - 1 \sim \left(\frac{l_c}{\sigma}\right)^2, \quad (C8)$$

with $l_c = \sqrt{\hbar/m_e^* \omega_c}$ the magnetic confinement length. At 5 T, $l_c \sim 10 \text{ nm}$, so this correction is also small. Finally, we have the diffusion parameter

$$D - 1 \approx \frac{\hbar^2 x_D^2}{4m_e^* \nu \alpha^2} \approx 10^{-5}, \quad (C9)$$

and the dispersion of the initial wave packet is also negligible.

Neglecting these small terms then, the arrival time distribution becomes that of a dispersionless Gaussian wave packet moving at velocity v_g and damped at a rate Γ_0 :

$$A(x_D, t) = \frac{1}{\sqrt{2\pi\alpha}} v_g e^{-\Gamma_0^{k_0} t} \exp\left[-\frac{1}{2\alpha}(x_D - v_g t)^2\right].$$

This agrees with the expression found in Sec. IV B and the lack of any significant corrections to this simple Gaussian evolution justifies the use of the semiclassical approach in the main text.

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